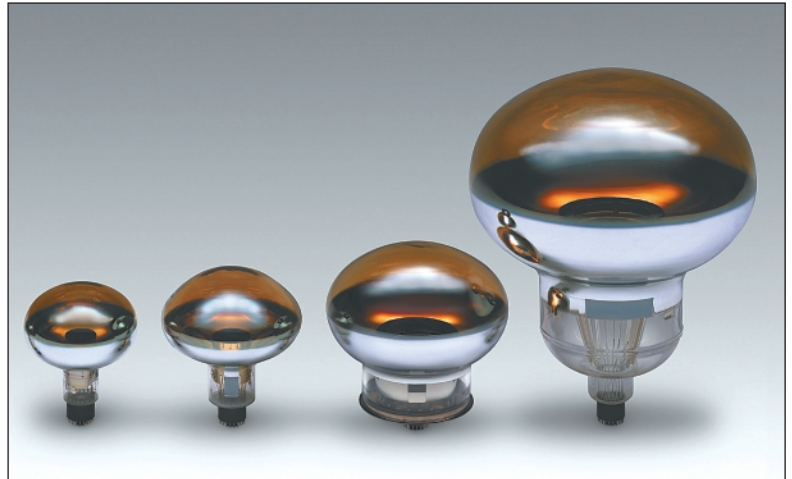


APPLICATION

- High energy physics

FEATURES

- Hemispherical window
- Fast time response
- High stability
- Low dark count



R5912
R5912-20
R5912-100

R7081
R7081-20
R7081-100

R8055

R3600-02
R7250

SPECIFICATIONS

Type No.	Diameter (mm) / (inch)	Minimum effective area (mm)	Surface area		Dynode		Weight (g)
			Min. (cm ²)	Typ. (cm ²)	Structure	Number of stages	
R5912	202 / 8	φ190	330	380	Box & Line	10	approx. 1100
R5912-20	202 / 8	φ190	330	380	Box & Line	14	approx. 1100
R5912-100	202 / 8	φ190	330	380	Box & Line	10	approx. 1100
R7081	253 / 10	φ220	470	530	Box & Line	10	approx. 1400
R7081-20	253 / 10	φ220	470	530	Box & Line	14	approx. 1400
R7081-100	253 / 10	φ220	470	530	Box & Line	10	approx. 1400
R8055	332 / 13	φ312	960	1080	Box & Line	10	approx. 3000
R3600-02	508 / 20	φ460	2030	2410	Venetian blind	11	approx. 8000
R7250	508 / 20	φ430	1680	1740	Box & Line	10	approx. 8000

COMMON SPECIFICATIONS

Parameter	Description / Value
Spectral response	300 nm to 650 nm
Peak wavelength	420 nm
Photocathode material	Bialkali
Window material	Borosilicate glass

LARGE PHOTOCATHODE AREA PHOTOMULTIPLIER TUBES

SPECIFICATIONS

Type No.	Cathode sensitivity					Anode sensitivity				
	Luminous (2856 K)		Radiant at 420 nm	Blue sensitivity index (CS 5-58)		Quantum efficiency at 390 nm	Luminous (2856 K)	Radiant at 420 nm	Gain	Applied voltage for typical gain
	Min. ($\mu\text{A/lm}$)	Typ. ($\mu\text{A/lm}$)		Typ. (mA/W)	Min.					
R5912	40	80	80	6.0	10.0	25	800	8.0×10^5	1.0×10^7	1500
R5912-20	40	80	80	6.0	10.0	25	80 000	8.0×10^7	1.0×10^9	1500
R5912-100	80	130	110	12.5	13.5	35	1300	1.1×10^6	1.0×10^7	1500
R7081	40	80	80	6.0	10.0	25	800	8.0×10^5	1.0×10^7	1500
R7081-20	40	80	80	6.0	10.0	25	80 000	8.0×10^7	1.0×10^9	1500
R7081-100	80	130	110	12.5	13.5	35	1300	1.1×10^6	1.0×10^7	1500
R8055	35	60	65	5.5	8.0	20	3000	3.25×10^6	5.0×10^7	2000
R3600-02	35	60	65	5.5	8.0	20	600	6.5×10^5	1.0×10^7	2000
R7250	35	60	65	5.5	8.0	20	600	6.5×10^5	1.0×10^7	2000

NOTE: Anode characteristics are measured with the voltage distribution ratio shown below.

Type No.	Maximum rating						Direct Interelectrode capacitances	
	Supply voltage		Average anode current (mA)	Operating ambient temperature ($^{\circ}\text{C}$)	Storage temperature ($^{\circ}\text{C}$)	Ambient pressure (Gauge) (MPa)	Anode to last dynode (pF)	Anode to all other dynodes (pF)
	Anode to cathode (V)	Anode to last dynode (V)						
R5912	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R5912-20	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R5912-100	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R7081	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R7081-20	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R7081-100	2000	300	0.1	-30 to +50	-30 to +50	0.7	approx. 3	approx. 7
R8055	2500	300	0.1	-30 to +50	-30 to +50	0.15	approx. 10	approx. 20
R3600-02	2500	300	0.1	-30 to +50	-30 to +50	0.6	approx. 36	approx. 40
R7250	2500	300	0.1	-30 to +50	-30 to +50	0.6	approx. 10	approx. 15

Anode sensitivity

(at +25 °C)

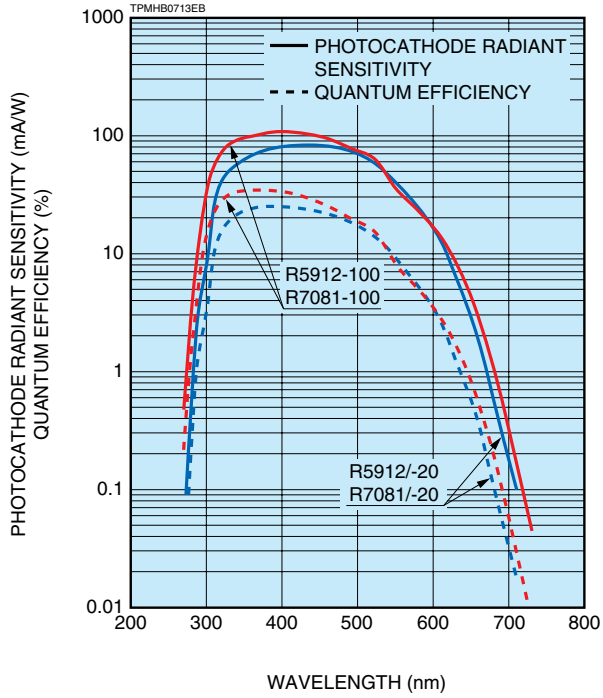
Dark current (After 30 min storage in darkness)		Dark count (After 15 hours storage in darkness)		Time response			Single photo-electron (Peak to valley ratio)		Pulse linearity		Type No.
Typ. (nA)	Max. (nA)	Typ. (s ⁻¹)	Max. (s ⁻¹)	Rise time	Electron transit time	Transit time spread (FWHM)	Min.	Typ.	at ±2 % Deviation	at ±5 % Deviation	
				Typ. (ns)	Typ. (ns)	Typ. (ns)			Typ. (mA)	Typ. (mA)	
100	1000	4000	8000	3.6	54	2.4	1.5	2.8	40	60	R5912
5000	10 000	6000	12 000	4.4	72	3.0	1.5	2.8	30	60	R5912-20
500	1000	6000	10 000	3.6	54	2.4	1.5	2.8	40	60	R5912-100
100	1000	7000	15 000	3.8	62	3.4	1.5	2.8	40	60	R7081
5000	10 000	9000	19 000	5.0	80	3.9	1.5	2.8	30	60	R7081-20
500	1000	8000	16 000	3.8	62	3.4	1.5	2.8	40	60	R7081-100
200	1000	15 000	30 000	5.3	88	2.8	1.5	2.5	60	80	R8055
200	1000	25 000	80 000	10.0	95	5.5	1.1	1.7	20	40	R3600-02
200	1000	25 000	80 000	7.0	110	3.5	1.5	2.5	60	80	R7250

Type No.	Supply voltage (V)	Voltage distribution ratio K: Photocathode Dy: Dynode P: Anode G: Grid																		
		K	Dy1	G2	G1	G3	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	P				
R5912/-100 R7081/-100	1500	16.8	0	0.6	0	3.4	5	3.33	1.67	1	1.2	1.5	2.2	3	2.4	Capacitors in μF 0.01 0.01 0.01				
R8055	2000	18.5	0	0.6	0	3.4	5	3.3	1.7	1	1	1	2	3	4	Capacitors in μF 0.01 0.01 0.01				
R7250	2000	18.5	0	0.6	0	3.4	5	3.3	1.7	1	1	1	2	3	4	Capacitors in μF 0.01 0.01 0.01				
R3600-02	2000	K	G2	G1	G3	Dy1	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	Dy11	P			
		5	1	2	0.02	3	1	1	1	1	1	1	1	1	1	1	Capacitors in μF 0.01 0.01 0.01			
R5912-20 R7081-20	1500	K	Dy1	G2	G1	G3	Dy2	Dy3	Dy4	Dy5	Dy6	Dy7	Dy8	Dy9	Dy10	Dy11	Dy12	Dy13	Dy14	P
		11.3	0	0.6	0	3.4	5	3.33	1.67	1	1	1	1	1	1.2	1.5	2.2	3	2.4	Capacitors in μF 0.01 0.01 0.01 0.02 0.02

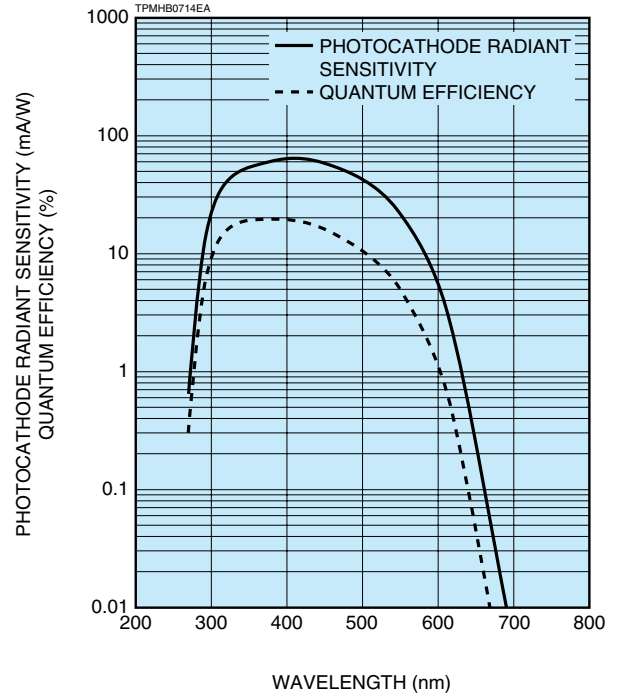
LARGE PHOTOCATHODE AREA PHOTOMULTIPLIER TUBES

SPECTRAL RESPONSE CHARACTERISTICS

- R5912/-20/-100
- R7081/-20/-100

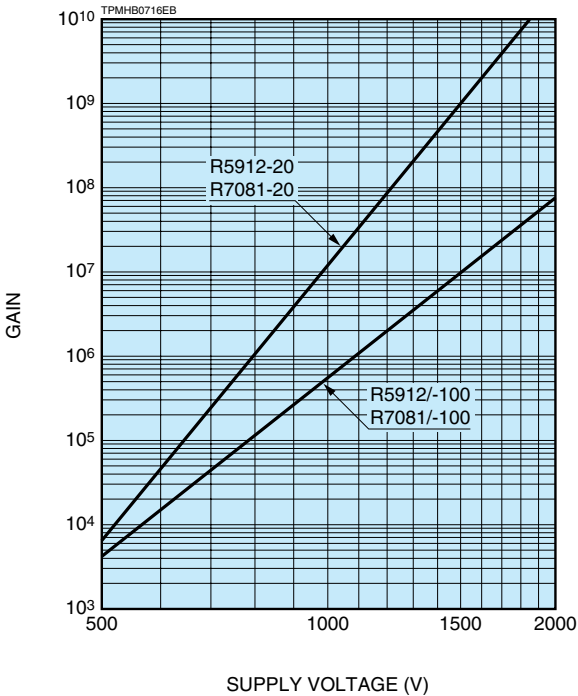


- R8055, R3600-02, R7250

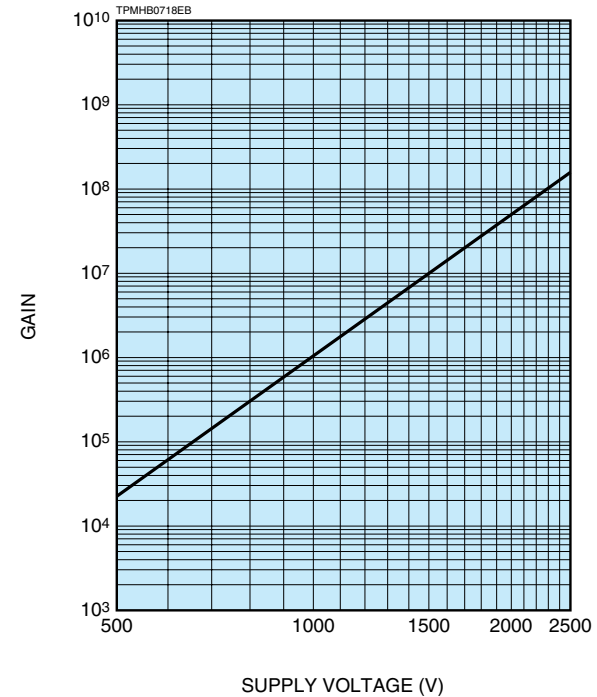


GAIN

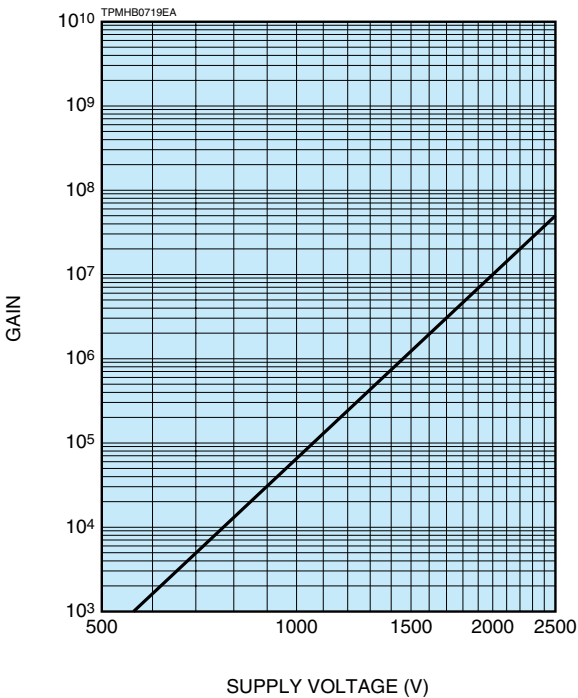
- R5912/-20/-100
- R7081/-20/-100



- R8055



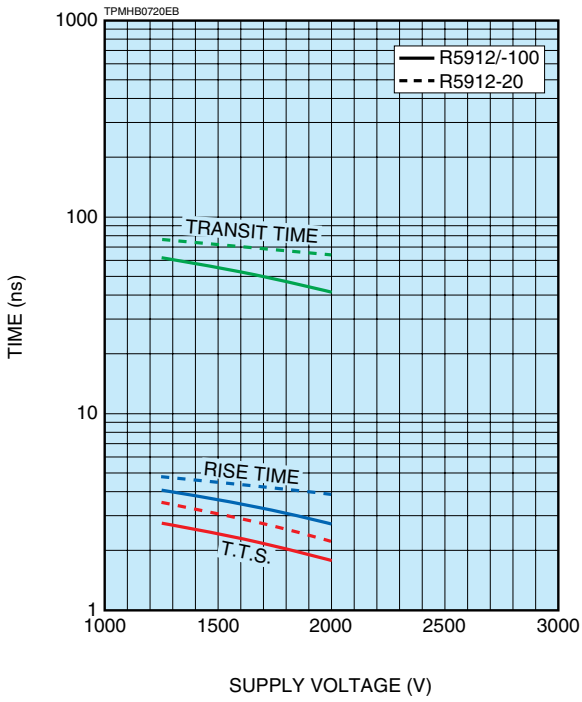
- R3600-02, R7250



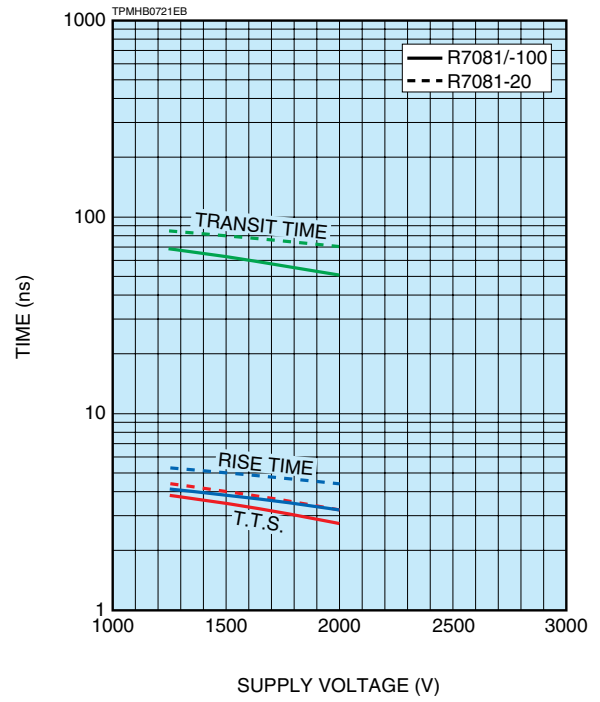
LARGE PHOTOCATHODE AREA PHOTOMULTIPLIER TUBES

TYPICAL TIME RESPONSE

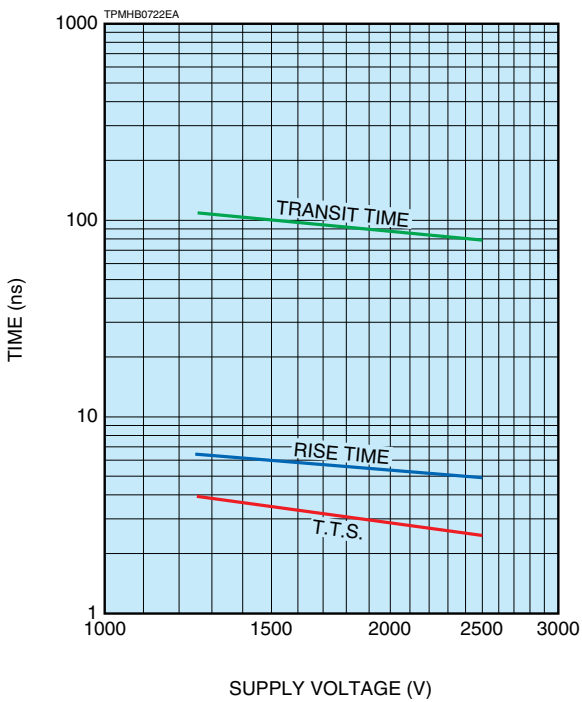
●R5912/-20/-100



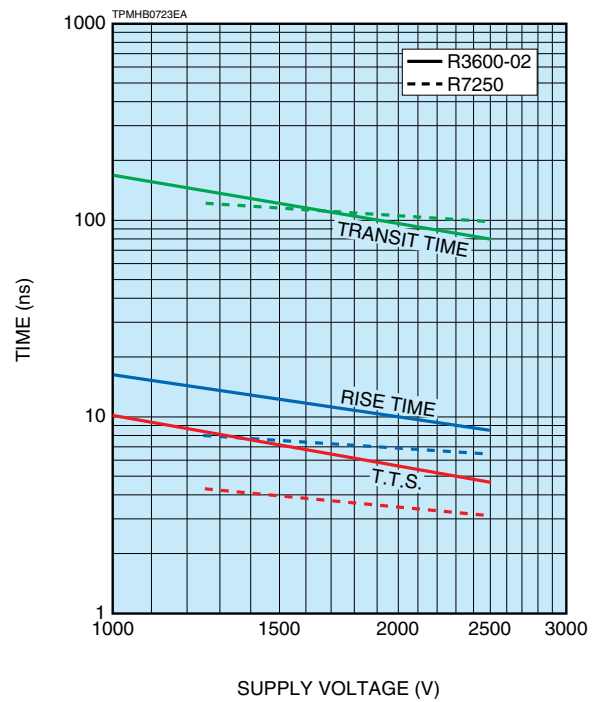
●R7081/-20/-100



●R8055

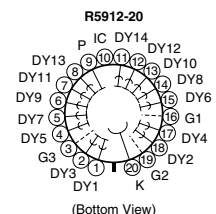
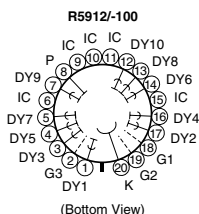
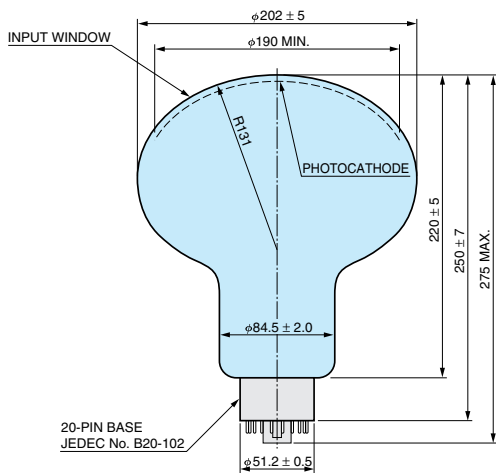


●R3600-02, R7250



DIMENSIONAL OUTLINE (Unit: mm)

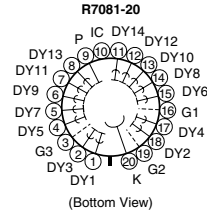
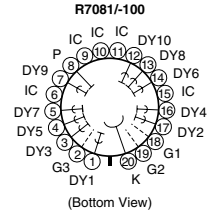
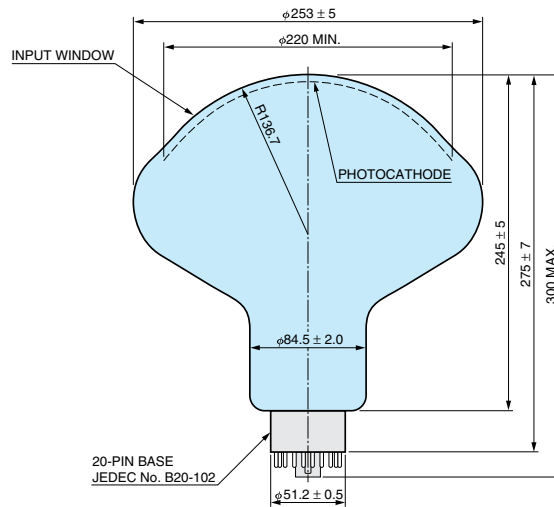
●R5912/-20/-100



IC: Internal Connection
(Do not use)

TPMHA0500EC

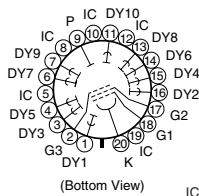
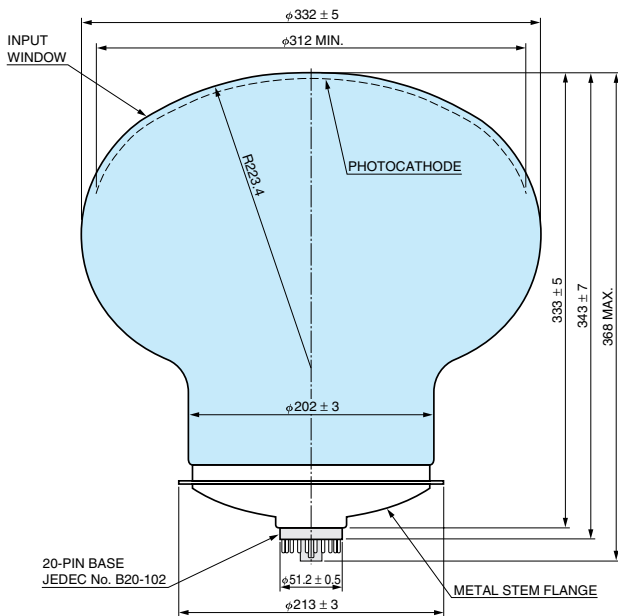
●R7081/-20/-100



IC: Internal Connection
(Do not use)

TPMHA0501EC

●R8055



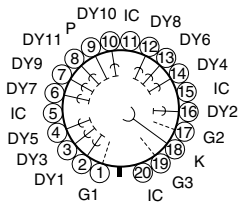
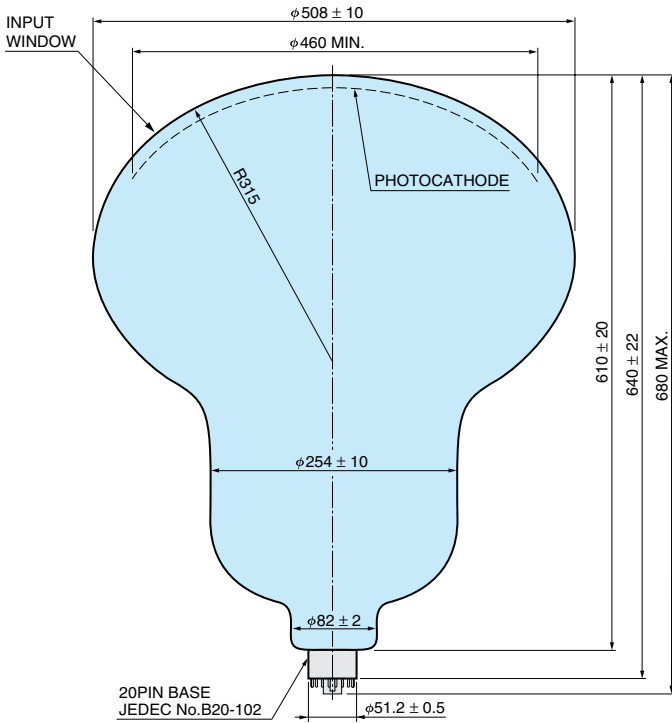
IC: Internal Connection
(Do not use)

TPMHA0502EC

LARGE PHOTOCATHODE AREA PHOTOMULTIPLIER TUBES

DIMENSIONAL OUTLINE (Unit: mm)

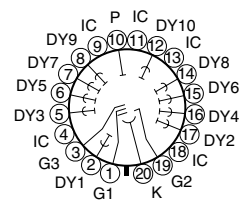
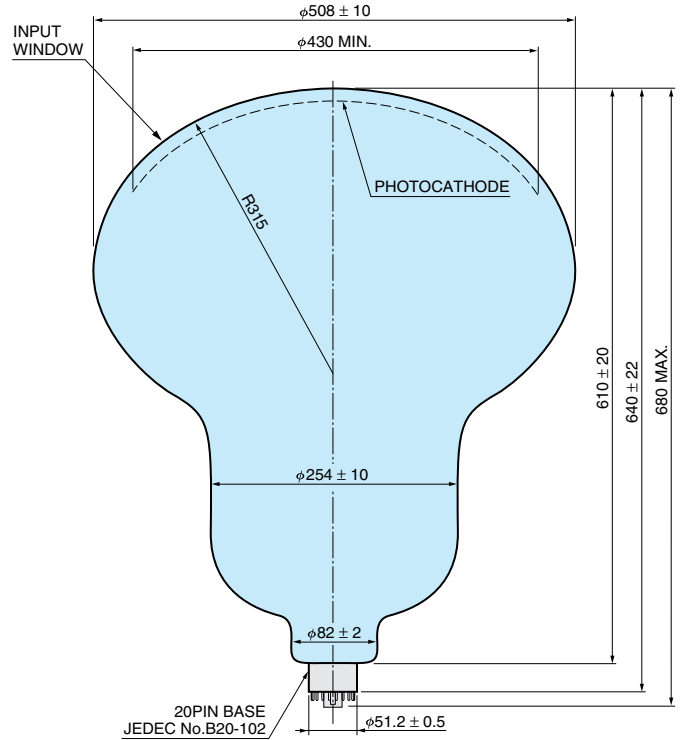
●R3600-02



IC: Internal Connection
(Do not use)

TPMHA0092EG

●R7250



IC: Internal Connection
(Do not use)

TPMHA0475EG

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